TABLE OF CONTENTS

REVISION HISTORY

2/08—Rev A to Rev B

Changes to Absolute Maximum Ratings Section, Table 3 5
Updated Outline Dimensions 12
Changes to Ordering Guide 12

4/06—Rev. 0 to Rev. A

Changes to Features Section 1
Changes to Product Highlights Section 1
Changes to Specifications Section 3
Changes to Typical Performance Characteristics 8

10/04—Revision 0: Initial Version

Downloaded from Arrow.com.

SPECIFICATIONS

SINGLE SUPPLY

V_{DD} = 5 V ± 10%, GND = 0 V. All specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 1.

Parameter	B Version[1] 25°C	B Version[1] T_{MIN} to T_{MAX}	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 to 2.5	V	
On Resistance, R_{ON}	5		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA; Figure 8
	7	8	Ω max	
On-Resistance Match Between Channels, ΔR_{ON}	0.4		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA
		1.2	Ω max	
On-Resistance Flatness, $R_{FLAT(ON)}$	0.7		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA
		1.35	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I_S (Off)	±0.001		nA typ	V_S = 3 V/1 V; V_D = 1 V/3 V; Figure 9
Drain Off Leakage, I_D (Off)	±0.001		nA typ	V_S = 3 V/1 V; V_D = 1 V/3 V; Figure 9
Channel On Leakage, I_D, I_S (On)	±0.001		nA typ	V_D = V_S = 3 V/1 V; Figure 10
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.0	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}	0.001		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
Digital Input Capacitance, C_{IN}		3	pF typ	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}, t_{ON} ($\overline{EN}$)	7		ns typ	C_L = 35 pF; R_L = 50 Ω
		14	ns max	V_S = 2 V; Figure 11
t_{OFF}, t_{OFF} ($\overline{EN}$)	5		ns typ	C_L = 35 pF; R_L = 50 Ω
		8	ns max	V_S = 2 V; Figure 11
Break-Before-Make Time Delay, t_D	3		ns typ	C_L = 35 pF; R_L = 50 Ω
		1	ns min	V_{S1} = V_{S2} = 2 V; Figure 12
Off Isolation	−65		dB typ	f = 10 MHz; R_L = 50 Ω; Figure 14
Channel-to-Channel Crosstalk	−70		dB typ	f = 10 MHz; R_L = 50 Ω; Figure 15
Bandwidth −3 dB	300		MHz typ	R_L = 50 Ω; Figure 13
THD + N	0.18		% typ	R_L = 100 Ω
Charge Injection	7.5		pC typ	C_L = 1 nF; V_S = 0 V; Figure 16
C_S (Off)	8		pF typ	
C_D (Off)	14		pF typ	
C_D, C_S (On)	23		pF typ	
POWER REQUIREMENTS				V_{DD} = 5.5 V; digital inputs = 0 V or V_{DD}
I_{DD}	0.001		μA typ	
		1	μA max	

[1] Temperature range for B version is −40°C to +85°C.
[2] Guaranteed by design, not subject to production test.

Downloaded from Arrow.com.

V_{DD} = 3 V ± 10%, GND = 0 V. All specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 2.

Parameter	B Version[1] 25°C	B Version[1] T_{MIN} to T_{MAX}	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 to 1.5	V	
On Resistance, R_{ON}	7		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA; Figure 8
	9.5	11	Ω max	
On-Resistance Match between Channels, ΔR_{ON}	0.3		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA
		0.9	Ω max	
On-Resistance Flatness, $R_{FLAT(ON)}$	2.6		Ω typ	V_D = 0 V to 1 V; I_S = −10 mA
		5	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I_S (Off)	±0.001		nA typ	V_S = 2 V/1 V; V_D = 1 V/2 V; Figure 9
Drain Off Leakage, I_D (Off)	±0.001		nA typ	V_S = 2 V/1 V; V_D = 1 V/2 V; Figure 9
Channel On Leakage, I_D, I_S (On)	±0.001		nA typ	V_D = V_S = 2 V/1 V; Figure 10
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.0	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}	0.001		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
Digital Input Capacitance, C_{IN}		3	pF typ	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}, t_{ON} ($\overline{EN}$)	10		ns typ	C_L = 35 pF; R_L = 50 Ω
		16	ns max	V_S = 1.5 V; Figure 11
t_{OFF}, t_{OFF} ($\overline{EN}$)	6		ns typ	C_L = 35 pF; R_L = 50 Ω
		10	ns max	V_S = 1.5 V; Figure 11
Break-Before-Make Time Delay, t_D	3		ns typ	C_L = 35 pF; R_L = 50 Ω
		1	ns min	V_{S1} = V_{S2} = 1.5 V; Figure 12
Off Isolation	−65		dB typ	f = 10 MHz; R_L = 50 Ω; Figure 14
Channel-to-Channel Crosstalk	−70		dB typ	f = 10 MHz; R_L = 50 Ω; Figure 15
Bandwidth −3 dB	300		MHz typ	R_L = 50 Ω; Figure 13
THD + N	0.18		% typ	R_L = 100 Ω
Charge Injection	4		pC typ	C_L = 1 nF; V_S = 0 V; Figure 16
C_S (Off)	8		pF typ	
C_D (Off)	14		pF typ	
C_D, C_S (On)	23		pF typ	
POWER REQUIREMENTS				V_{DD} = 3.3 V; digital inputs = 0 V or V_{DD}
I_{DD}	0.001		μA typ	
		1	μA max	

[1] Temperature range for B version is −40°C to +85°C.
[2] Guaranteed by design, not subject to production test.

Downloaded from Arrow.com.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 3.

Parameters	Ratings
V_{DD} to GND	−0.3 V to +6 V
Analog, Digital Inputs[1]	−0.3 V to V_{DD} + 0.3 V or 30 mA, whichever occurs first
Continuous Current, S or D	100 mA
Peak Current, S or D	300 mA (pulsed at 1 ms, 10% duty cycle maximum)
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
QSOP Package, Power Dissipation	566 mW
θ_{JA} Thermal Impedance	149.97°C/W
Lead Temperature, Soldering	
Reflow, Peak Temperature	260(+0/−5)°C
Time at Peak Temperature	20 sec to 40 sec

[1] Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating may be applied at any one time.

Table 4. Truth Table

$\overline{EN}$	IN	D1	D2	D3	D4	Function
1	X	High-Z	High-Z	High-Z	High-Z	Disable
0	0	S1A	S2A	S3A	S4A	IN = 0
0	1	S1B	S2B	S3B	S4B	IN = 1

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Downloaded from Arrow.com.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

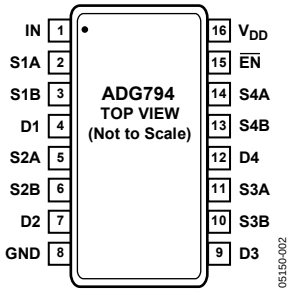


Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin N0.	Mnemonic	Description
1	IN	Logic Control Input. The logic level at this input controls the operation of the multiplexers (see Table 4).
2	S1A	A-Side Source Terminal of Mux1. Can be an input or an output.
3	S1B	B-Side Source Terminal of Mux1. Can be an input or an output.
4	D1	Drain Terminal of Mux1. Can be an input or an output.
5	S2A	A-Side Source Terminal of Mux2. Can be an input or an output.
6	S2B	B-Side Source Terminal of Mux2. Can be an input or an output.
7	D2	Drain Terminal of Mux2. Can be an input or an output.
8	GND	Ground Reference.
9	D3	Drain Terminal of Mux3. Can be an input or an output.
10	S3B	B-Side Source Terminal of Mux3. Can be an input or an output.
11	S3A	A-Side Source Terminal of Mux3. Can be an input or an output.
12	D4	Drain Terminal of Mux4. Can be an input or an output.
13	S4B	B-Side Source Terminal of Mux4. Can be an input or an output.
14	S4A	A-Side Source Terminal of Mux4. Can be an input or an output.
15	$\overline{EN}$	Mux Enable Logic Input. Enables or disables the multiplexers (see Table 4).
16	V_{DD}	Positive Power Supply Voltage.

Downloaded from Arrow.com.

TERMINOLOGY

V_{DD}

Most positive power supply potential.

I_{DD}
Positive supply current.

GND
Ground (0 V) reference.

S
Source terminal. Can be either an input or an output.

D
Drain terminal. Can be either an input or an output.

IN
Logic control input.

V_D (V_S)
Analog voltage on Terminal D and Terminal S.

R_{ON}
Ohmic resistance between Terminal D and Terminal S.

$R_{FLAT (ON)}$
Flatness is defined as the difference between the maximum and minimum value of on resistance as measured.

ΔR_{ON}
On-resistance match between any two channels.

I_S (Off)
Source leakage current with the switch off.

I_D (Off)
Drain leakage current with the switch off.

I_D, I_S (On)
Channel leakage current with the switch on.

V_{INL}
Maximum input voltage for Logic 0.

V_{INH}
Minimum input voltage for Logic 1.

I_{INL} (I_{INH})
Input current of the digital input.

C_S (Off)
Off switch source capacitance. Measured with reference to ground.

C_D (Off)
Off switch drain capacitance. Measured with reference to ground.

C_D, C_S (On)
On switch capacitance. Measured with reference to ground.

C_{IN}
Digital input capacitance.

t_{ON}
Delay time between the 50% and the 90% points of the digital input and switch on condition.

t_{OFF}
Delay time between the 50% and the 90% points of the digital input and switch off condition.

t_{BBM}
On or off time measured between the 80% points of both switches when switching from one to another.

Charge Injection
A measure of the glitch impulse transferred from the digital input to the analog output during on/off switching.

Off Isolation
A measure of unwanted signal coupling through an off switch.

Crosstalk
A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

−3 dB Bandwidth
The frequency at which the output is attenuated by 3 dB.

On Response
The frequency response of the on switch.

Insertion Loss
The loss due to the on resistance of the switch.

THD + N
The ratio of the harmonic amplitudes plus the noise of a signal to the fundamental.

Downloaded from Arrow.com.

TYPICAL PERFORMANCE CHARACTERISTICS

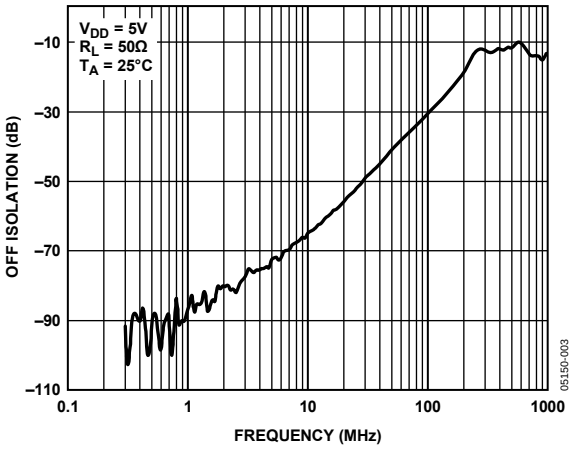


Figure 3. Off Isolation vs. Frequency

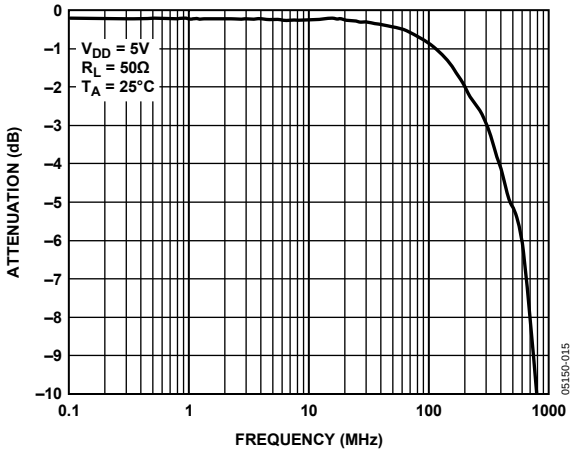


Figure 5. Bandwidth

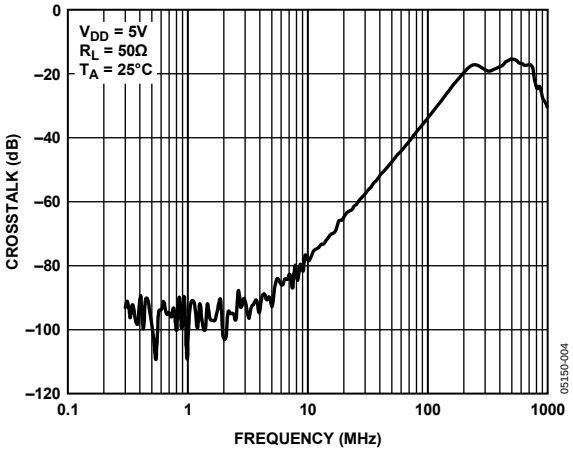


Figure 4. Crosstalk vs. Frequency

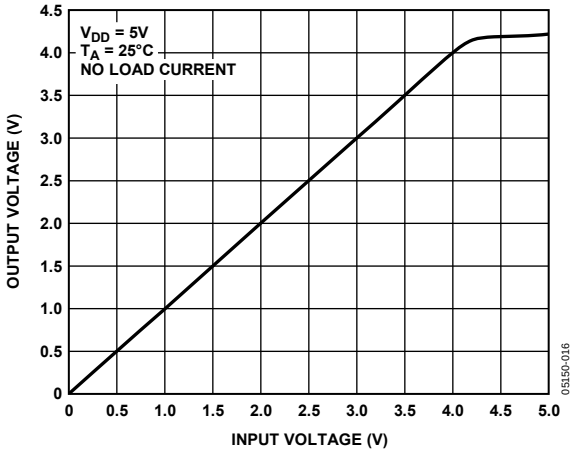


Figure 6. Output Voltage vs. Input Voltage

Downloaded from Arrow.com.

TYPICAL APPLICATION

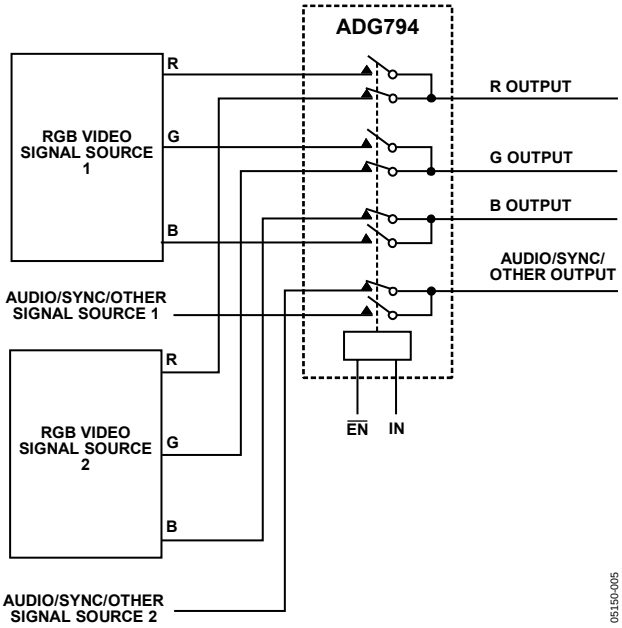


Figure 7. Audio/Video Switch

Downloaded from Arrow.com.

TEST CIRCUITS

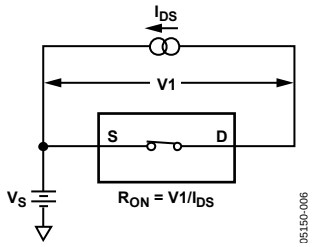


Figure 8. On Resistance

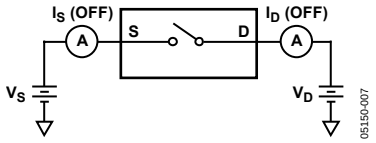


Figure 9. Off Leakage

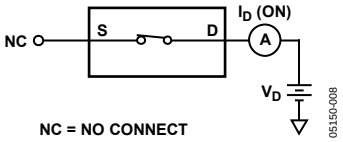


Figure 10. On Leakage

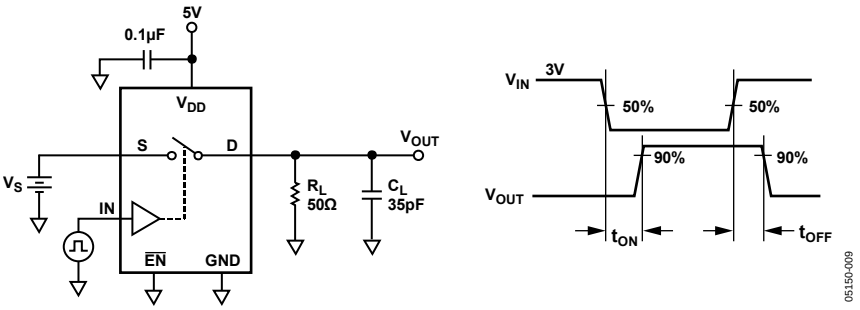


Figure 11. Switching Times

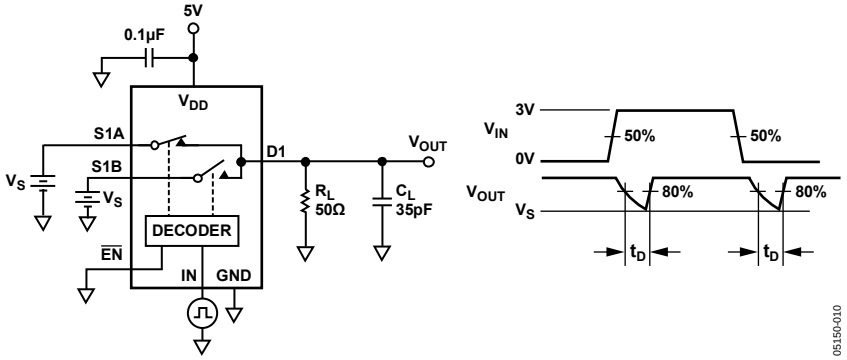


Figure 12. Break-Before-Make Time Delay

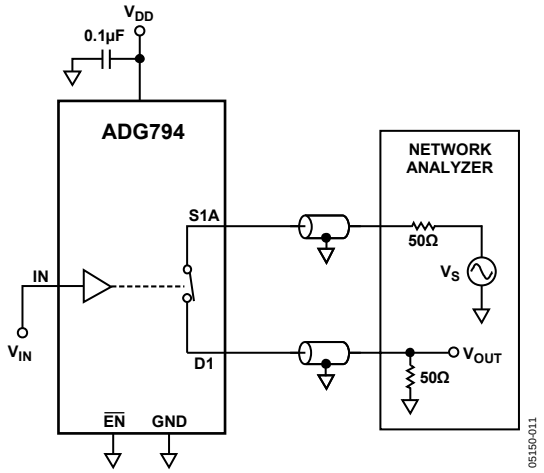


Figure 13. Bandwidth

Downloaded from Arrow.com.

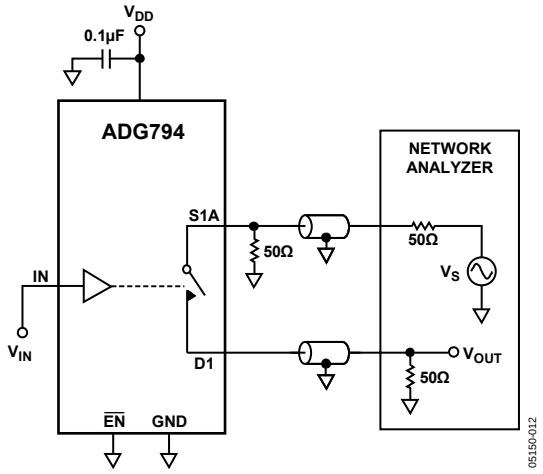


Figure 14. Off Isolation

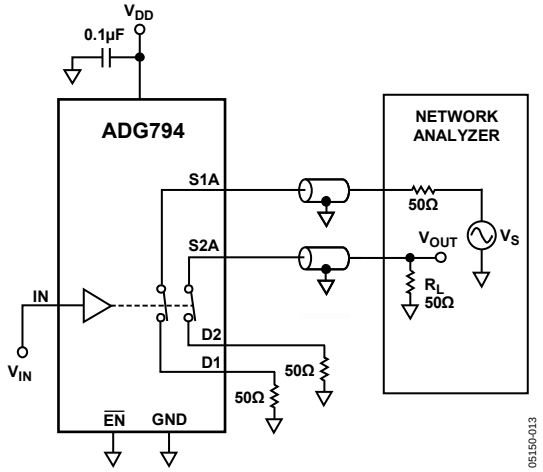


Figure 15. Channel-to-Channel Crosstalk

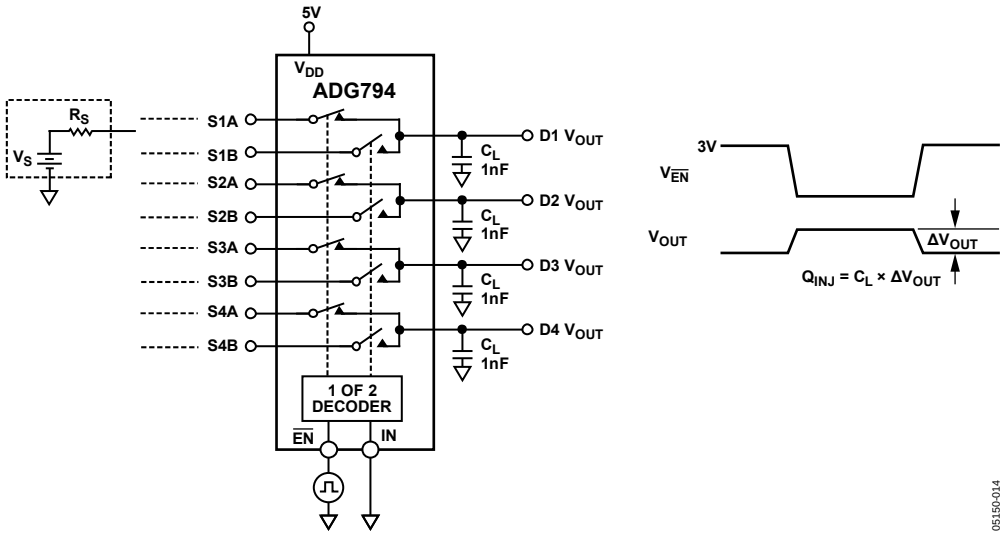
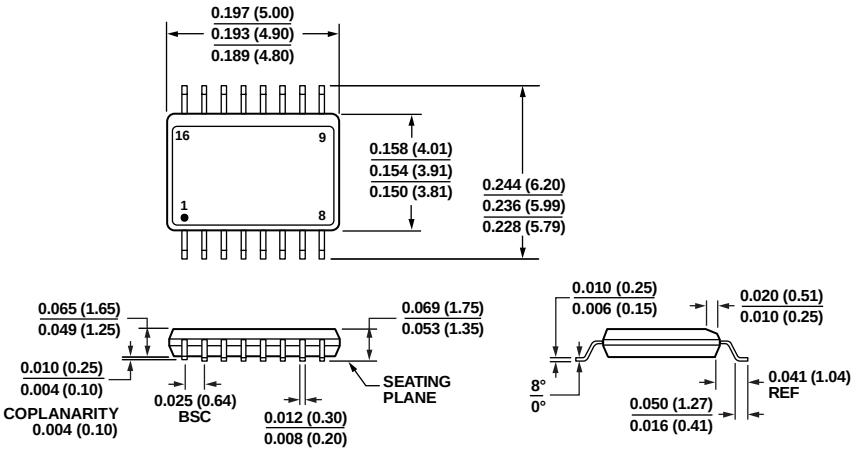


Figure 16. Charge Injection

Downloaded from Arrow.com.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-137-AB

CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETERS DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

012808-A

Figure 17. 16-Lead Shrink Small Outline Package [QSOP]
(RQ-16)
Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG794BRQZ[1]	−40°C to +85°C	16-Lead Shrink Small Outline Package (QSOP)	RQ-16
ADG794BRQZ-500RL7[1]	−40°C to +85°C	16-Lead Shrink Small Outline Package (QSOP)	RQ-16
ADG794BRQZ-REEL[1]	−40°C to +85°C	16-Lead Shrink Small Outline Package (QSOP)	RQ-16
ADG794BRQZ-REEL7[1]	−40°C to +85°C	16-Lead Shrink Small Outline Package (QSOP)	RQ-16

[1] Z = RoHS Compliant Part.

©2004–2008 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners.
D05150-0-2/08(B)

Downloaded from Arrow.com.